



DUAL P-CHANNEL ENHANCEMENT MODE MOSFET

This device contains two electrically-isolated P-channel, enhancement-mode MOSFETs, housed in a very small SOT-363 (SC70-6L) package. This device is ideal for portable applications where board space is at a premium.

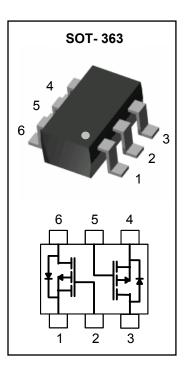
FEATURES

- Low On-Resistance
- Low Gate Threshold Voltage
- Fast Switching
- Lead free in compliance with EU RoHS 2011/65/EU directive
- Green molding compound as per IEC61249 Std. . (Halogen Free)

APPLICATIONS

- Switching Power Supplies
- Hand-Held Computers, PDAs

MARKING CODE: S84



MAXIMUM RATINGS

 T_{\perp} = 25°C Unless otherwise noted

Rating	Symbol	Value	Units
Drain-Source Voltage	V _{DSS}	- 50	V
Drain-Gate Voltage (Note 1)	V_{DGR}	- 50	V
Gate-Source Voltage	V _{GSS}	± 20	V
Drain Current	I _D	130	mA
Total Power Dissipation (Note 2)	PD	200	mW
Operating Junction Temperature Range	TJ	-55 to +150	°C
Storage Temperature Range	T _{stg}	-55 to +150	°C

Note 1. R_{GS} < 20K ohms

THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Units
Thermal Resistance, Junction to Ambient (Note 2)	R _{thja}	625	°C/W

Note 2. FR-4 board 70 x 60 x 1mm with minimum recommended pad layout





Electrical Characteristics (Each Device)

 $T_J = 25$ °C Unless otherwise noted

OFF CHARACTERISTICS (Note 3)

Parameter	Symbol	Conditions	Min	Тур	Max	Units
Drain-Source Breakdown Voltage	BV _{DSS}	I _D = -250μA, V _{GS} = 0V	-50	-	-	V
		V_{DS} = -50V, V_{GS} = 0V, $T_{\overline{J}}$ 25°C	-	-	-15	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = -50V, V _{GS} = 0V, T _J =125°C	-	-	-60	μΑ
		V _{DS} = -25V, V _{GS} = 0V, T _J =25°C	-	-	-0.1	
Gate-Body Leakage	I _{GSS}	V _{GS} = ±20V, V _{DS} = 0V	-	-	±10	nA

ON CHARACTERISTICS (Note 3)

Parameter	Symbol	Conditions	Min	Тур	Max	Units
Gate Threshold Voltage	V _{GS(th)}	V _{DS} = V _{G§} I _D = -1mA	-0.8	-1.44	-2.0	V
Static Drain-Source On-Resistance	R _{DS(ON)}	V _{GS} = -5V, I _D = -0.1A	-	3.8	10	Ohms
Forward Transconductance	9 _{FS}	V _{DS} = -25V, I _D = -0.1A	0.05	-	-	S

DYNAMIC CHARACTERISTICS

Parameter	Symbol	Conditions	Min	Тур	Max	Units
Input Capacitance	C _{iss}	V _{DS} = -25V, V _{GS} = 0V, f = 1.0MHz	-	-	45	pF
Output Capacitance	Coss		-	-	25	pF
Reverse Transfer Capacitance	C _{rss}		-	-	12	pF

SWITCHING CHARACTERISTICS

Parameter	Symbol	Conditions	Min	Тур	Max	Units
Turn-On Delay Time	t _{D(ON)}	V_{DD} = -30V, I $_{D}$ = -0.27A, R _{GEN} = 50ohm, V _{GS} = -10V	-	7.5	-	ns
Turn-Off Delay Time	t _{D(OFF)}		-	25	-	ns

Note 3. Short duration test pulse used to minimize self-heating





Electrical Characteristic Curves (Each Device)

T_J = 25°C Unless otherwise noted

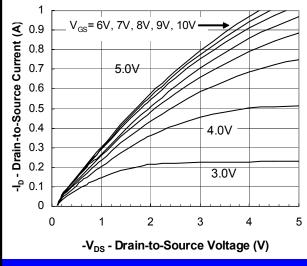


Fig. 1. Output Characteristics

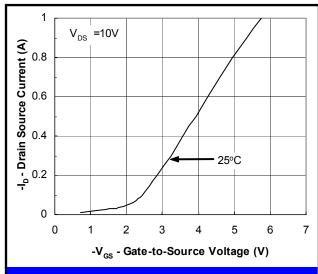


Fig. 2. Transfer Characteristics

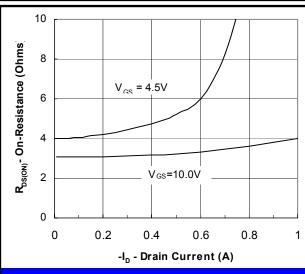


Fig. 3. On-Resistance vs. Drain Current

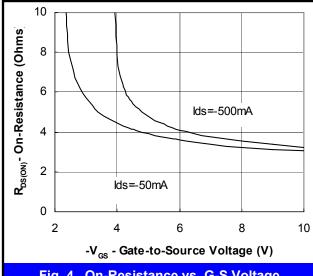
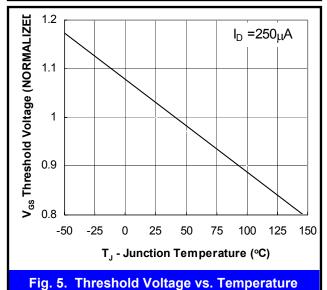


Fig. 4. On-Resistance vs. G-S Voltage



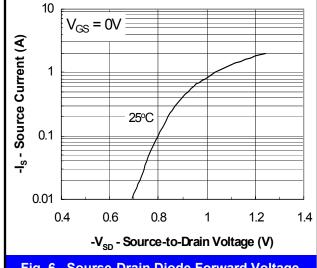
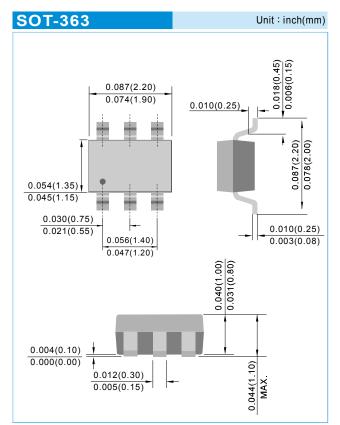


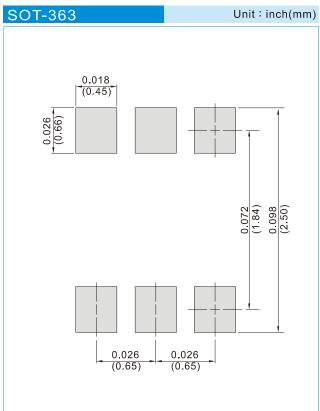
Fig. 6. Sourse-Drain Diode Forward Voltage





PACKAGE LAYOUT AND SUGGESTED PAD DIMENSIONS





ORDERING INFORMATION

BSS84DW T/R7 - 7 inch reel, 3K units per reel

BSS84DW T/R13 - 13 inch reel, 10K units per reel





BSS84DW

Part No_packing code_Version

BSS84DW_R1_00001 BSS84DW_R2_00001

For example:



Packing Code XX					Version Code XXXXX			
Packing type	1 st Code	Packing size code	2 nd Code	HF or RoHS	1 st Code	2 nd ~5 th Code		
Tape and Ammunition Box (T/B)	Α	N/A	0	HF	0	serial number		
Tape and Reel (T/R)	R	7"	1	RoHS	1	serial number		
Bulk Packing (B/P)	В	13"	2					
Tube Packing (T/P)	Т	26mm	X					
Tape and Reel (Right Oriented) (TRR)	S	52mm	Y					
Tape and Reel (Left Oriented) (TRL)	L	PANASERT T/B CATHODE UP (PBCU)	U					
FORMING	F	PANASERT T/B CATHODE DOWN (PBCD)	D					

May 25,2016-REV.01 PAGE . 5





BSS84DW

Disclaimer

- Reproducing and modifying information of the document is prohibited without permission from Panjit International Inc..
- Panjit International Inc. reserves the rights to make changes of the content herein the document anytime without notification. Please refer to our website for the latest document.
- Panjit International Inc. disclaims any and all liability arising out of the application or use of any product including damages incidentally and consequentially occurred.
- Panjit International Inc. does not assume any and all implied warranties, including warranties
 of fitness for particular purpose, non-infringement and merchantability.
- Applications shown on the herein document are examples of standard use and operation.
 Customers are responsible in comprehending the suitable use in particular applications.
 Panjit International Inc. makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.
- The products shown herein are not designed and authorized for equipments requiring high level of reliability or relating to human life and for any applications concerning life-saving or life-sustaining, such as medical instruments, transportation equipment, aerospace machinery et cetera. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Panjit International Inc. for any damages resulting from such improper use or sale.
- Since Panjit uses lot number as the tracking base, please provide the lot number for tracking when complaining.

May 25,2016-REV.01 PAGE . 6

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for MOSFET category:

Click to view products by Panjit manufacturer:

Other Similar products are found below:

614233C 648584F MCH3443-TL-E MCH6422-TL-E FDPF9N50NZ NTNS3A92PZT5G IRFD120 IRFF430 JANTX2N5237 2N7000
AOD464 2SK2267(Q) 2SK2545(Q,T) 405094E 423220D MIC4420CM-TR VN1206L 614234A 715780A SSM6J414TU,LF(T 751625C IPS70R2K0CEAKMA1 BSF024N03LT3 G PSMN4R2-30MLD TK31J60W5,S1VQ(O 2SK2614(TE16L1,Q) DMN1017UCP3-7
EFC2J004NUZTDG FCAB21350L1 P85W28HP2F-7071 DMN1053UCP4-7 NTE2384 NTE2969 NTE6400A DMC2700UDMQ-7
DMN2080UCB4-7 DMN61D9UWQ-13 US6M2GTR DMN31D5UDJ-7 SSM6P54TU,LF DMP22D4UFO-7B IPS60R3K4CEAKMA1 DMN1006UCA6-7 DMN16M9UCA6-7 STF5N65M6 IRF40H233XTMA1 IPSA70R950CEAKMA1 IPSA70R2K0CEAKMA1 STU5N65M6 C3M0021120D